### Vishay Semiconductors



Schottky Rectifier, 1.0 A



Cathode		Anode
<u> </u>	-	o

PRODUCT SUMMARY				
Package	SMB			
I <sub>F(AV)</sub>	1.0 A			
V <sub>R</sub>	40 V			
V <sub>F</sub> at I <sub>F</sub>	0.38 V			
I <sub>RM</sub>	9 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	3.0 mJ			

### FEATURES

• Low forward voltage drop



RoHS

COMPLIANT HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-10BQ040-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	1.0	А		
V <sub>RRM</sub>		40	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	430	А		
V <sub>F</sub>	1.0 Apk, T <sub>J</sub> = 125 °C	0.38	V		
TJ	Range	- 55 to 150	°C		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10BQ040-M3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	40	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 122 °C, rectangular waveform		1.0	А
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	430	A
	IFSM	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	40	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1		1 A	T <sub>1</sub> = 25 °C	0.45	V
	V (1)	2 A	1j=25 C	0.52	
	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>J</sub> = 125 °C	0.38	
		2 A		0.50	
Maximum reverse leakage current		T <sub>J</sub> = 25 °C		0.1	mA
See fig. 2	I <sub>RM</sub>	T <sub>J</sub> = 125 °C	$V_R = Rated V_R$	9.0	
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ , (test signal range 100 kHz to 1 MHz), 25 °C		115	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of charge	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

 $^{(1)}\,$  Pulse width = 300  $\mu s,$  duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 55 to 150	°C
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>	DC operation	36	°C/W
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>		80	C/W
Approximate weight			0.10	g
		0.003	oz.	
Marking device		Case style SMB (similar DO-214AA)	1	F

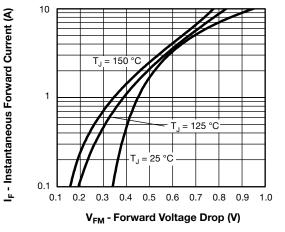
### Notes

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

<sup>(2)</sup> Mounted 1" square PCB

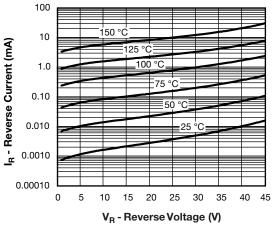


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Fig. 1 - Maximum Forward Voltage Drop Characteristics





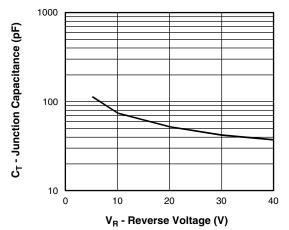


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

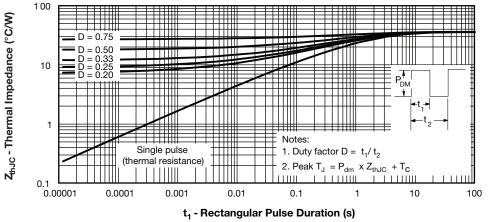
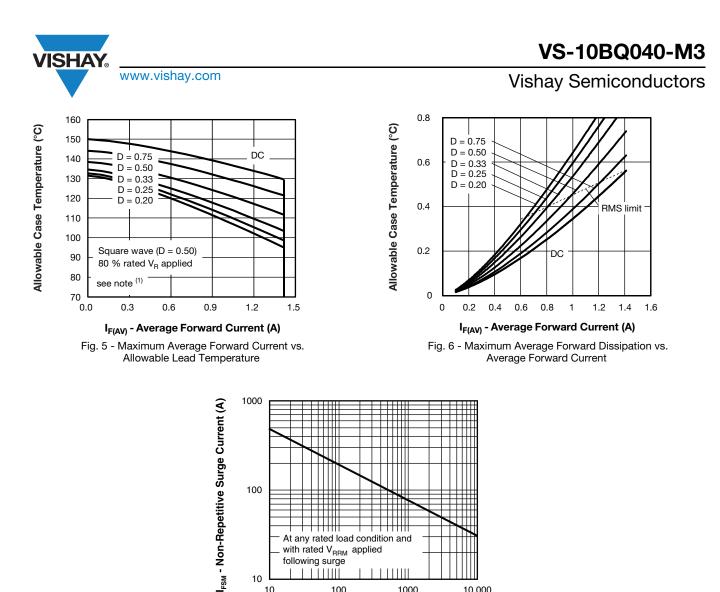


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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At any rated load condition and with rated  $V_{\text{RRM}}$  applied following surge 

100

t<sub>p</sub> - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

1000

10 000

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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Document Number: 93335

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Device code	VS-	10	В	Q	040	-M3
		2	3	4	5	6
	1 · 2 ·		hay Sen rent rati		ctors pro	oduct
	3 -	в=	SMB	0		
	4 -	Q =	Schottk	ky "Q" se	eries	
	5 -	Vol	tage rati	ng (040	= 40 V)	)
	6 -	- Env	vironmer	ntal digit	:	
				~		

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION				
VS-10BQ040-M3/5BT	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95401			
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		



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